MSC030SDA070K

Datasheet

Zero Recovery Silicon Carbide Schottky Diode

Final April 2018



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1 Revision History

The revision history describes the changes that were implemented in the document. The changes are listed by revision, starting with the most current publication.

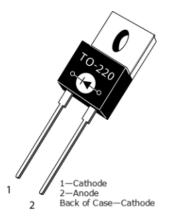
1.1 Revision A

Revision A was published in April 2018. It is the first publication of this document.



2 Product Overview

This section shows the product overview for the MSC030SDA070K device.



2.1 Features

The following are key features of the MSC030SDA070K device:

- Ultra-fast recovery times
- Soft recovery characteristics
- Low forward voltage
- Low leakage current
- Avalanche energy rated
- RoHS compliant

2.2 Benefits

The following are benefits of the MSC030SDA070K device:

- High switching frequency
- Low switching losses
- Low noise (EMI) switching
- Higher reliability systems
- Increased system power density

2.3 Applications

The MSC030SDA070K device is designed for the following applications:

- Power Factor Correction (PFC)
- Anti-parallel diode
 - Switch-mode power supply
 - Inverters/converters
 - Motor controllers
- Freewheeling diode
 - Switch-mode power supply
 - Inverters/converters
- Snubber/clamp diode



3 Electrical Specifications

This section shows the electrical specifications for the MSC030SDA070K device.

3.1 Absolute Maximum Ratings

The following table shows the absolute maximum ratings for the MSC030SDA070K device. All ratings: $T_c = 25$ °C unless otherwise specified.

Table 1 • Absolute Maximum Ratings

Symbol	Parameter	Ratings	Unit
VR	Maximum DC reverse voltage	700	V
VRRM	Maximum peak repetitive reverse voltage	700	
VRWM	Maximum working peak reverse voltage	700	
lf	Maximum DC forward current (Tc = 25 °C)	56	A
	Maximum DC forward current (Tc = 135 °C)	24	
	Maximum DC forward current (Tc = 145 °C)	19	
Ifrm	Repetitive peak forward surge current ($Tc = 25$ °C, $t_p = 8.3$ ms, half sine wave)	79	
IFSM	Non-repetitive forward surge current ($T_c = 25$ °C, $t_p = 8.3$ ms, half sine wave)	146	
P _{tot}	Power dissipation (Tc = 25 °C)	167	W
	Power dissipation (Tc = 110 °C)	72	
TJ , TSTG	Operating junction and storage temperature range	-55 to 175	°C
Τι	Lead temperature for 10 seconds	300	
Eas	Single pulse avalanche energy (starting Tı = 25 °C, L = 0.22 mH, peak I∟ = 30 A)	100	mJ

The following table shows the thermal and mechanical characteristics of the MSC030SDA070K device.

Table 2 • Thermal and Mechanical Characteristics

Symbol	Characteristic	Тур	Max	Unit
Rejc	Junction-to-case thermal resistance	0.62	0.9	°C/W
WT	Package weight	0.07		oz
		1.9		g
Torque	Maximum mounting torque		10	lbf-in
			1.1	N-m



3.2 Electrical Performance

The following table shows the static characteristics of the MSC030SDA070K device.

Table 3 • Static Characteristics

Symbol	Characteristic	Test Conditions	Тур	Max	Unit
VF	Forward voltage	IF = 30 A, TJ = 25 °C	1.5	1.8	V
		IF = 30 A, TJ = 175 °C	1.75		_
Irm	Reverse leakage current	V _R = 700 V, T _J = 25 °C	1	200	μA
		V _R = 700 V, T _J = 175 °C	10		
Qc	Total capacitive charge	V _R = 400 V, T _J = 25 °C	83		nC
C	Junction capacitance	$V_{R} = 1 V, T_{J} = 25 \text{ °C}, f = 1 MHz$	1200		pF
		V _R = 200 V, T _J = 25 °C, f = 1 MHz	150		_
		V _R = 400 V, T _J = 25 °C, f = 1 MHz	128		-



3.3 Performance Curves

This section shows the typical performance curves for the MSC030SDA070K device.

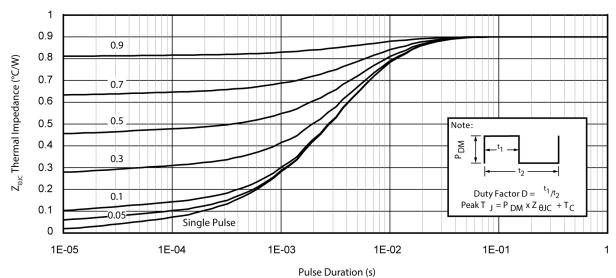


Figure 1 • Maximum Transient Thermal Impedance



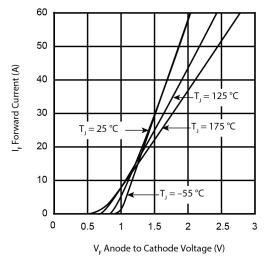
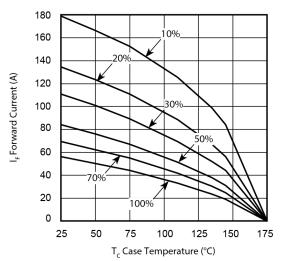


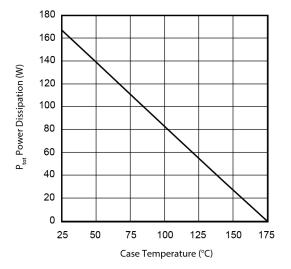
Figure 3 • Max. Forward Current vs. Case Temp.





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Figure 4 • Max. Power Dissipation vs. Case Temp.





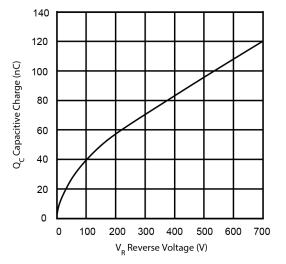
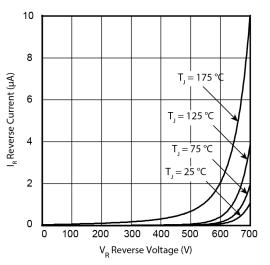
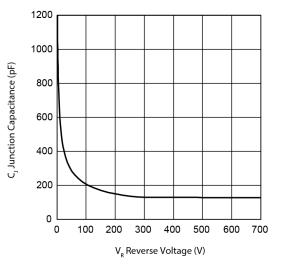


Figure 5 • Reverse Current vs. Reverse Voltage









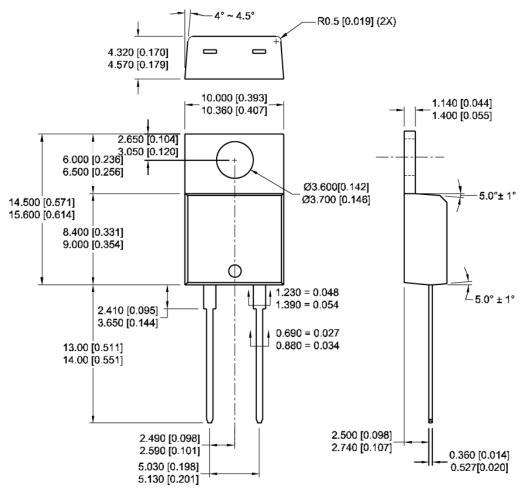
4 Package Specification

This section outlines the package specification for the MSC030SDA070K device.

4.1 Package Outline Drawing

This section details the TO-220 package drawing of the MSC030SDA070K device. Dimensions are in millimeters and (inches).

Figure 8 • Package Outline Drawing







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